

Product Summary

The GESDBW24VD34 is ultra low capacitance transient voltage suppressor arrays, designed to protect applications such as portable electronics and SMART phones. This series is available in both unidirectional and bidirectional configurations and is rated at 350 Watts for an 8/20 μ s waveform.

The GESDBW24VD34 meets IEC61000-4-2(ESD) and IEC61000-4-4(EFT) requirements. At higher operating frequencies or faster edge rates, insertion loss and signal integrity are a major concern. This series offers an ultra low capacitance and low leakage current in a miniature SOD-323 package.

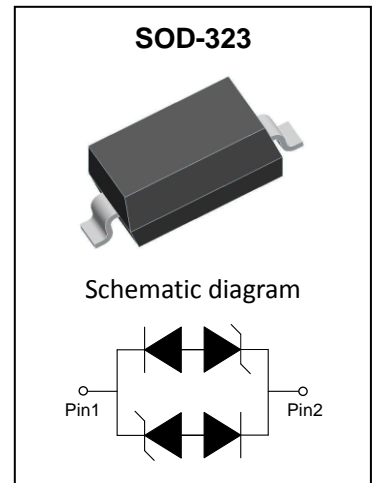
Feature

- Low reverse stand-off voltage: 24.0V
- Low reverse clamping voltage
- Low leakage current
- Fast response time
- JESD22-A114-B ESD Rating of class 3B per human body model
- IEC 61000-4-2 Level 4 ESD protection

Application

- Hand-Held Portable Applications
- Networking and Telecom(Ethernet 10/100/1000 Base T)
- USB Interface
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

Marking: HC



Absolute Maximum Ratings ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
IEC 61000-4-2 ESD Voltage Air Model	$V_{\text{ESD}}^{1)}$	± 30	kV
IEC 61000-4-2 ESD Voltage Contact Model		± 30	
JESD22-A114-B ESD Voltage Per Human Body Model		± 16	
ESD Voltage Machine Model		± 0.4	
Peak Pulse Power	$P_{\text{PP}}^{2)}$	350	W
Peak Pulse Current	$I_{\text{PP}}^{2)}$	6	A
Lead Solder Temperature – Maximum (10 Second Duration)	T_L	260	$^{\circ}\text{C}$
Junction Temperature	T_j	150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-55~ +150	$^{\circ}\text{C}$

- 1) Device stressed with ten non-repetitive ESD pulses.
- 2) Non-repetitive current pulse $8/20\mu\text{s}$ exponential decay waveform according to IEC61000-4-5.

ESD standards compliance

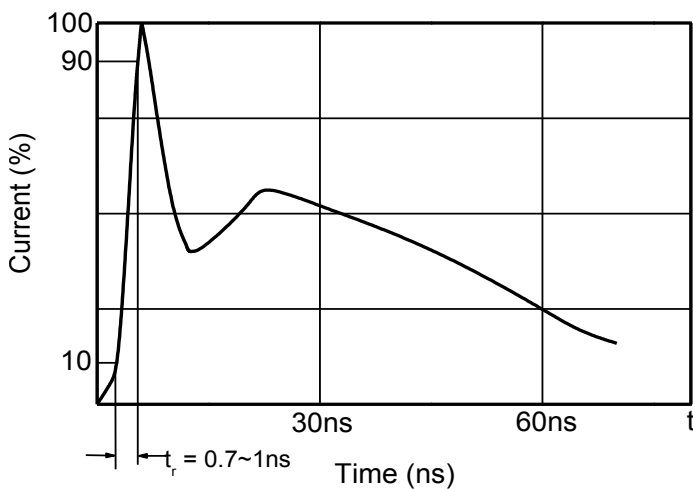
IEC61000-4-2 Standard

Contact Discharge		Air Discharge	
Level	Test Voltage kV	Level	Test Voltage kV
1	2	1	2
2	4	2	4
3	6	3	8
4	8	4	15

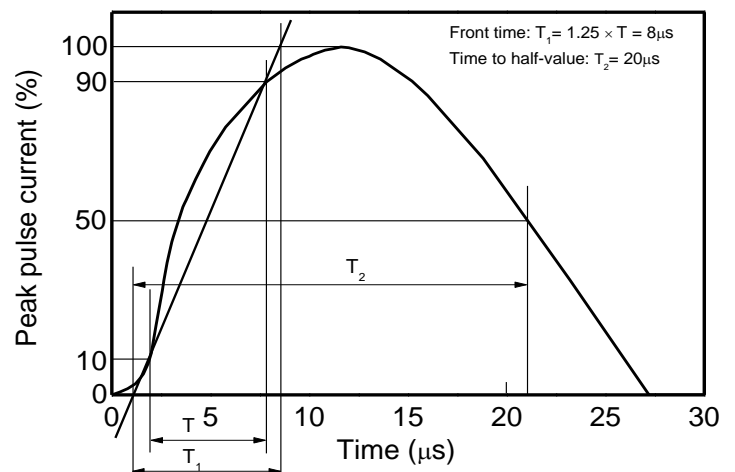
JESD22-A114-B Standard

ESD Class	Human Body Discharge V
0	0~249
1A	250~499
1B	500~999
1C	1000~1999
2	2000~3999
3A	4000~7999
3B	8000~15999

Contact discharge current waveform per IEC61000-4-2

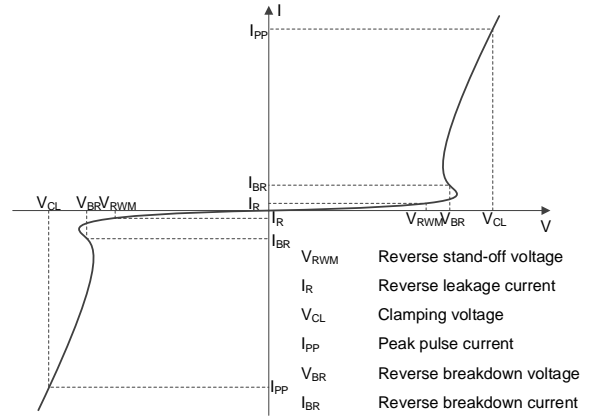


8/20μs waveform per IEC61000-4-5



Electrical Parameter

Symbol	Parameter
V _C	Clamping Voltage @ I _{PP}
I _{PP}	Peak Pulse Current
V _{BR}	Breakdown Voltage @ I _{BR}
I _{BR}	Test Current
I _R	Reverse Leakage Current @ V _{RWM}
V _{RWM}	Reverse Standoff Voltage



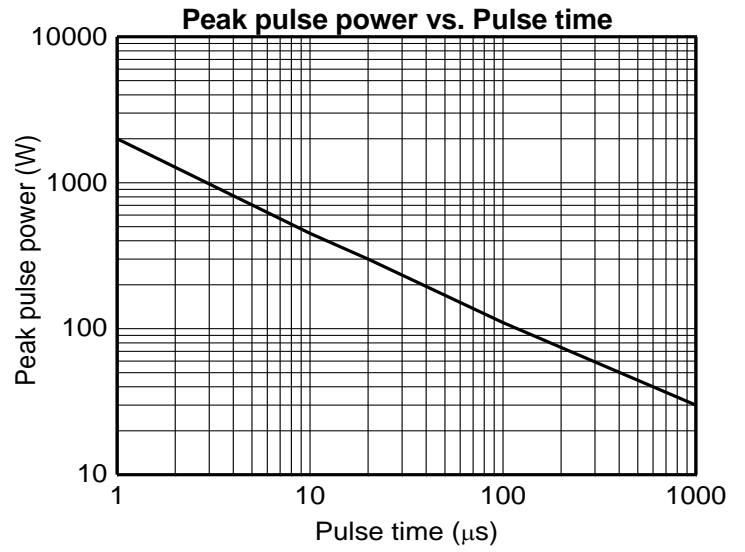
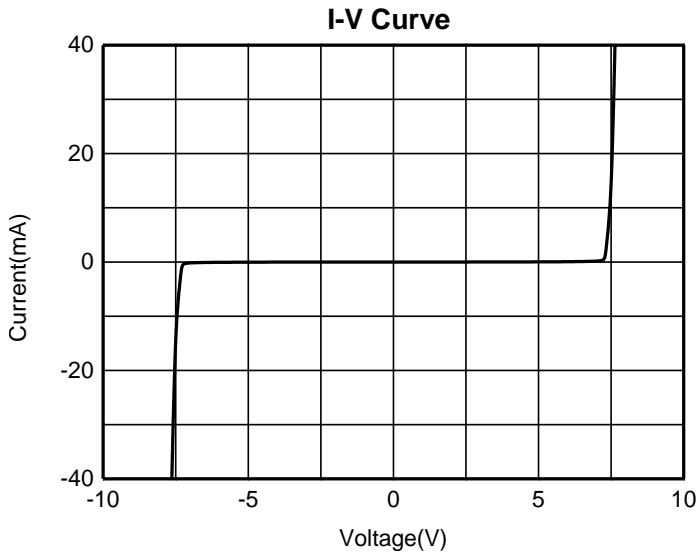
V-I characteristics for a Bi-directional TVS

Electrical Characteristics (Ta=25°C unless otherwise specified)

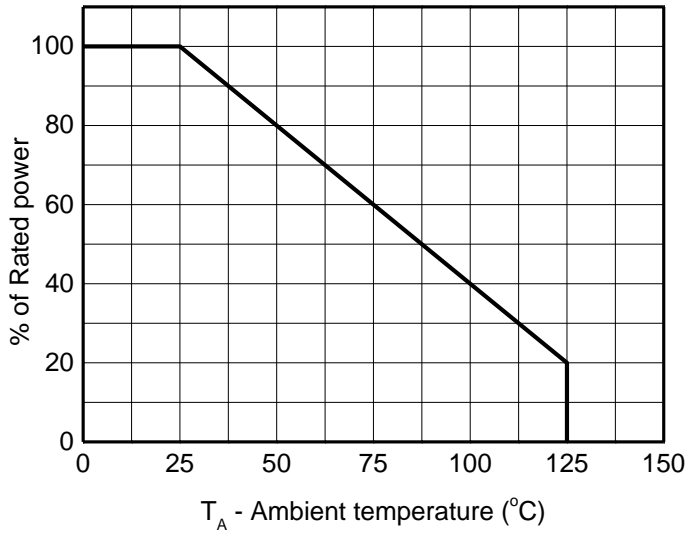
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse stand-off voltage	V _{RWM} ¹⁾				24	V
Reverse leakage current	I _R	V _{RWM} =5V			1	uA
Breakdown voltage	V _{BR}	I _T =1mA	26.7			V
Clamping voltage	V _C ²⁾	I _{PP} =6A		38		V
Junction capacitance	C _J	V _R =0V, f=1MHz		0.8	1.5	pF

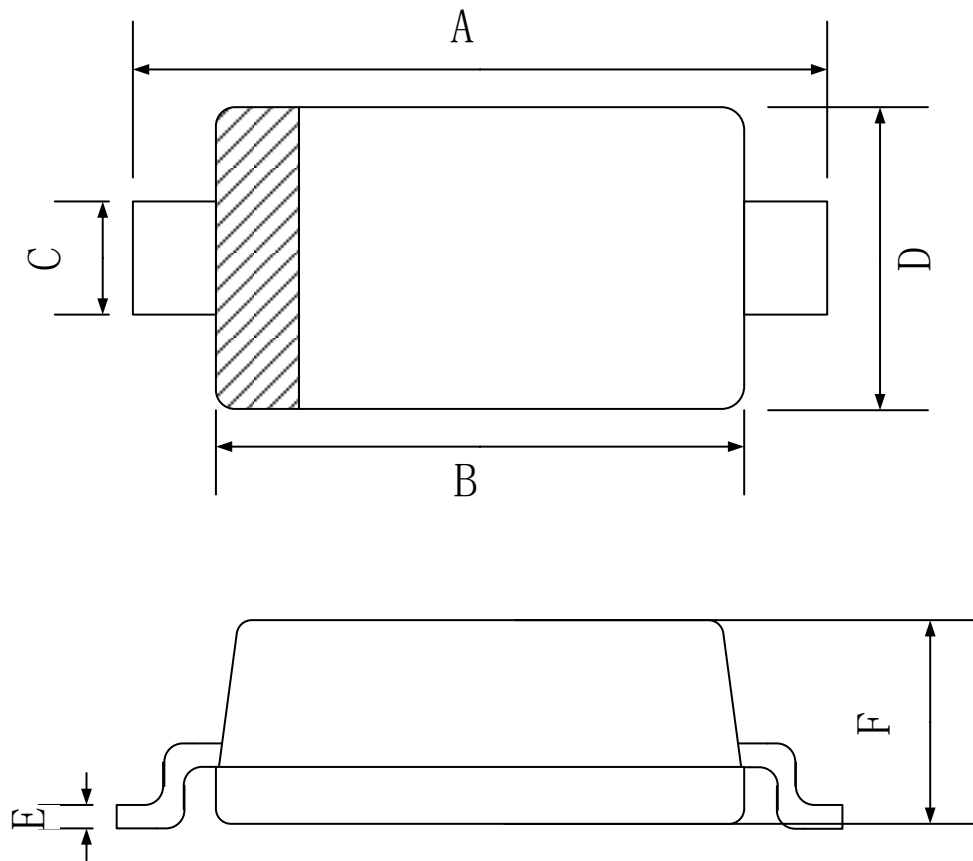
- 1) Other voltages available upon request.
- 2) Non-repetitive current pulse 8/20μs exponential decay waveform according to IEC61000-4-5

Typical Characteristics



Power derating vs. Ambient temperature



SOD-323 Package Outline Dimensions


Symbol	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	2.30	2.50	2.70
B	1.60	1.70	1.90
C	0.25	0.325	0.40
D	1.15	1.25	1.35
E	0.089	0.095	0.101
F	0.80	0.90	1.00

单击下面可查看定价，库存，交付和生命周期等信息

[>>GP\(格瑞宝\)](#)